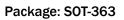
SGA4263Z



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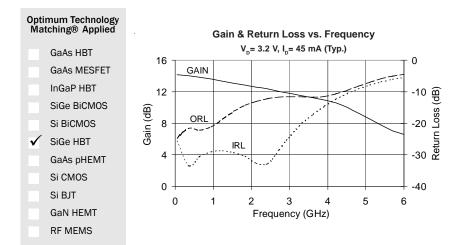
DC to 3500 MHz, CASCADABLE SiGe HBT **MMIC AMPLIFIER**





Product Description

The SGA4263Z is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high F_T and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.



Features

- Broadband Operation: DC to 3500MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Parameter	Specification			Unit	Condition	
Farameter	Min.	Тур.	Max.	Unit	Condition	
Small Signal Gain	12.5	14.0	15.5	dB	850MHz	
		12.7		dB	1950MHz	
		12.4		dB	2400MHz	
Output Power at 1dB Compression		14.2		dBm	850MHz	
		12.5		dBm	1950MHz	
Output Third Intercept Point		29.3		dBm	850MHz	
		25.7		dBm	1950MHz	
Bandwidth Determined by Return Loss		3500		MHz	>10dB	
Input Return Loss		31.3		dB	1950MHz	
Output Return Loss		13.8		dB	1950MHz	
Noise Figure		3.7		dB	1950MHz	
Device Operating Voltage	2.9	3.2	3.5	V		
Device Operating Current	41	45	49	mA		
Thermal Resistance (Junction - Lead)		255		°C/W		

Test Conditions: $V_S = 8V$, $I_D = 45$ mA Typ., OIP₃ Tone Spacing = 1MHz, P_{OUT} per tone = -5 dBm, $R_{BIAS} = 110\Omega$, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$

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SGA4263Z



Absolute Maximum Ratings

Rating	Unit
90	mA
5	V
+18	dBm
+150	°C
-40 to +85	°C
+150	°C
	90 5 +18 +150 -40 to +85

Operation of this device beyond any one of these limits may cause permanent dam-age. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:

 $I_D V_D < (T_J - T_L) / R_{TH}$, j-l

Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions ney reaction of the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

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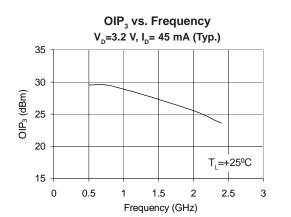


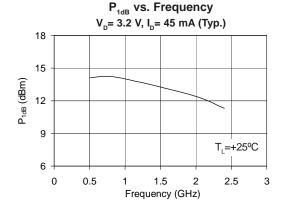
RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000 ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Typical Performance with 2.45 GHz Application Circuit

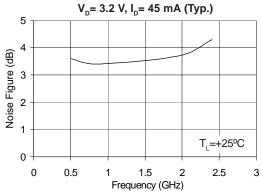
Parameter	Unit	100	500	850	1950	2400	3500
		MHz	MHz	MHz	MHz	MHz	MHz
Small Signal Gain	dB	14.1	13.9	14.0	12.7	12.4	11.3
Output Third Order Intercept Point	dBm		29.5	29.3	25.7	23.6	
Output Power at 1dB Compression	dBm		14.1	14.2	12.5	11.3	
Input Return Loss	dB	27.5	31.8	29.4	31.3	33.1	18.3
Output Return Loss	dB	23.4	22.0	21.7	13.8	12.2	11.7
Reverse Isolation	dB	17.7	18.3	18.5	19.0	19.0	18.2
Noise Figure	dB		3.6	3.4	3.7	4.3	

Test Conditions: $V_S = 8V$, $I_D = 45$ mA Typ., OIP₃ Tone Spacing = 1MHz, P_{OUT} per tone = -10dBm, $R_{BIAS} = 100\Omega$, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$



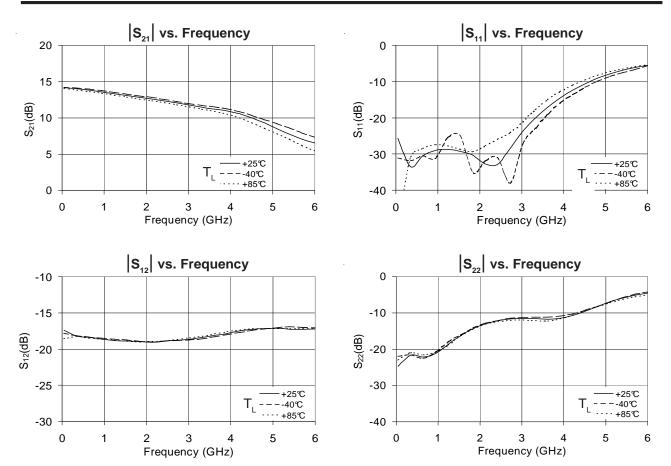


Noise Figure vs. Frequency



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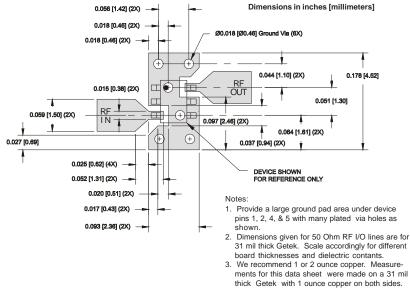
Typical RF Performance Over Temperature (Bias: V_{D} = 3.2 V, I_{D} = 45 mA (Typ.))

SGA4263Z

RFMD (IN)

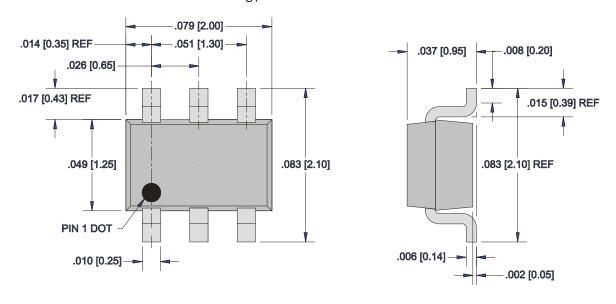
Pin	Function	Description
3	RF IN	RF input pin. This pin requires the use of an external DC-blocking capacitor chosen for the frequency of operation.
1, 2, 4, 5	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance as close to ground leads as possible.
6	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefor a DC-blocking capacitor is necessary for proper opera- tion.

Suggested Pad Layout



Package Drawing

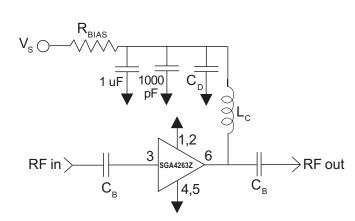
Dimensions in inches (millimeters) Refer to drawing posted at www.rfmd.com for tolerances.







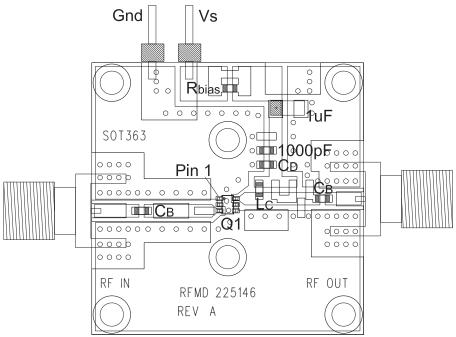
Application Schematic



Reference	Frequency (Mhz)						
Designator	500	850	1950	2400	3500		
C _B	220 pF	100 pF	68 pF	56 pF	39 pF		
C _D	100 pF	68 pF	22 pF	22 pF	15 pF		
L _c	68 nH	33 nH	22 nH	18 nH	15 nH		

Recommended Bias Resistor Values for $I_D = 45mA$ $R_{BIAS} = (V_S - V_D) / I_D$				
Supply Voltage(V _S)	6 V	8 V	10 V	12 V
R _{BIAS} 62 Ω 110 Ω 150 Ω 200 Ω				
Note: R _{BMS} provides DC bias stability over temperature.				

Evaluation Board Layout



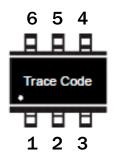
Mounting Instructions:

1. Use a large ground pad area near device pins 1, 2, 4, and 5 with many plated through-holes, as shown.

2. We recommend 1 or 2 ounces copper. Measurements for this data sheet were made on a 31mil thick FR-4 board with 1 ounce cooper on both sides.



Part Identification Marking



Ordering Information

Ordering Code	Description
SGA4263Z	7" Reel with 3000 pieces
SGA4263ZSQ	Sample bag with 25 pieces
SGA4263ZSR	7" Reel with 100 pieces
SGA4263ZPCK1	850MHz, 8V Operation PCBA with 5-piece sample bag